

Time-modulated arrays for smart WPT

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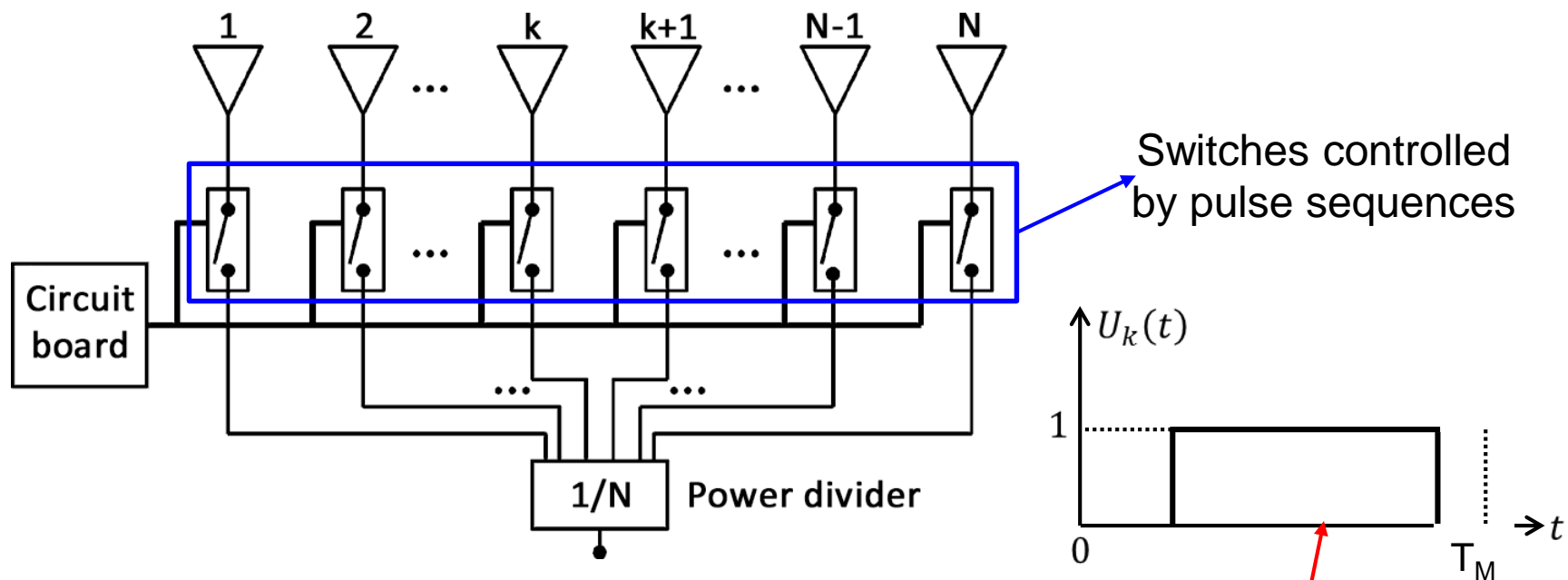
DEI – University of Bologna, Italy

Graz, March 30, 2015

Outline

- ***Time-modulated arrays (TMAs)*** architecture
- TMAs possible applications
- Description of the nonlinear/electromagnetic CAD tool for time-modulated array (TMA) analysis/design
- ***Smart WPT*** with TMA

TMA architecture



Array factor of a standard linear array

$$AF(\theta, \phi) = \sum_{k=1}^N \Lambda_k e^{j\delta_k} e^{jk\beta L \cos\psi}$$

Array factor of a linear TMA

$$AF(\theta, \phi, t) = \sum_{k=1}^N \Lambda_k e^{j\delta_k} U_k(t) e^{jk\beta L \cos\psi}$$

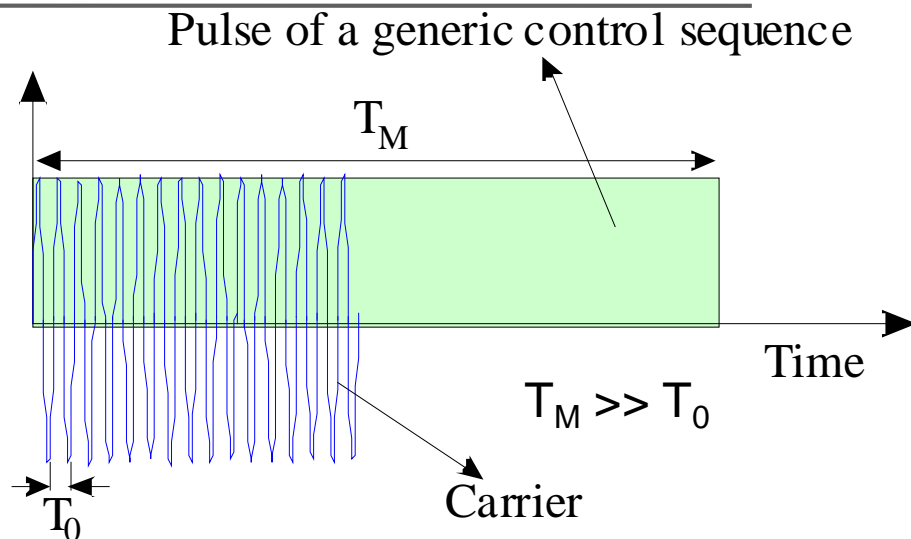
TMA regime

- T_M, f_M : period and frequency of switch modulation
- T_0, f_0 : period and frequency of *sinusoidal* RF carrier

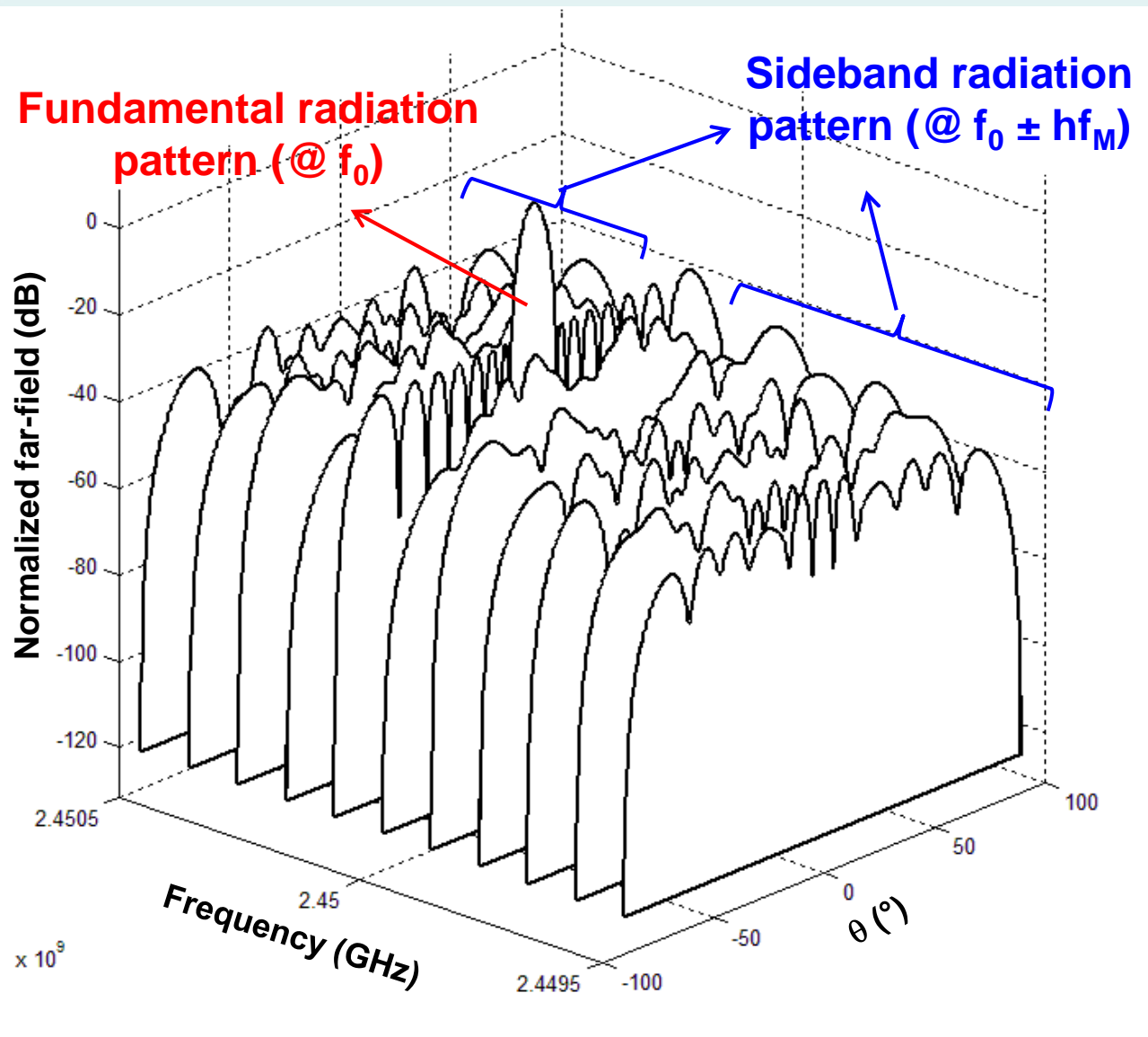


$$AF(\theta, \phi, t) = \sum_{h=-\infty}^{\infty} AF_h(\theta, \phi, t) = \sum_{h=-\infty}^{\infty} e^{j2\pi(f_0 + hf_M)t} \sum_{k=0}^{n-1} \Lambda_k u_{hk} e^{jk\beta L \cos \psi}$$

The superimposed switch modulation makes the array able to radiate not only at the **fundamental carrier ($h=0$)**, but also at the **sideband harmonics ($h \neq 0$)**



TMA radiation



TMA high reconfigurability

- The use of **time** as a further design parameter allows an almost unlimited control sequence combinations in TMAs

- The ease of implementation (no phase-shifters)



***Antenna reconfiguration
in real time!***

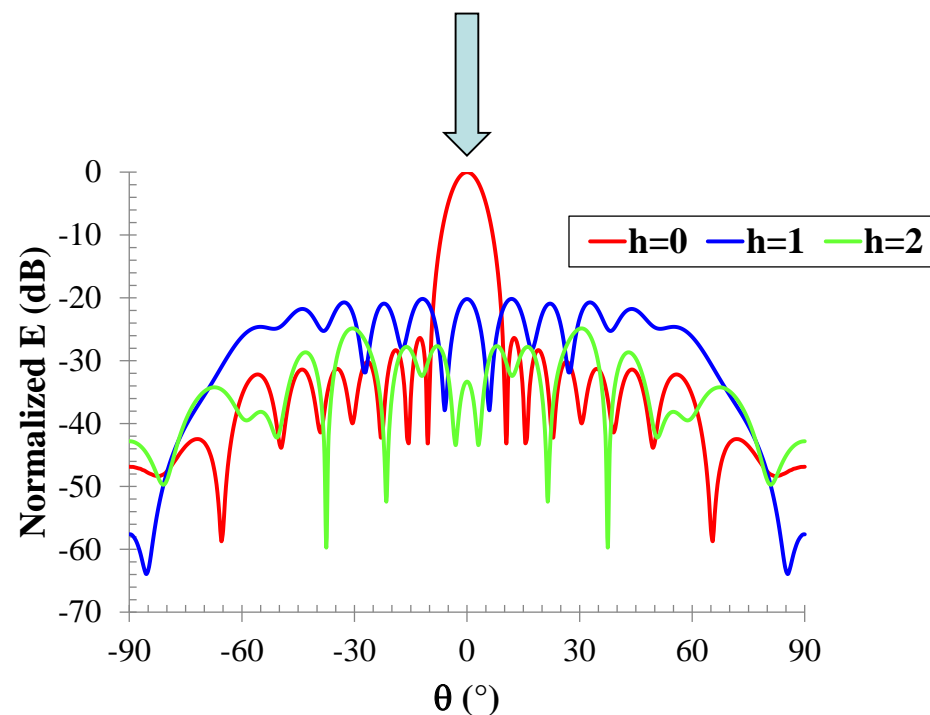
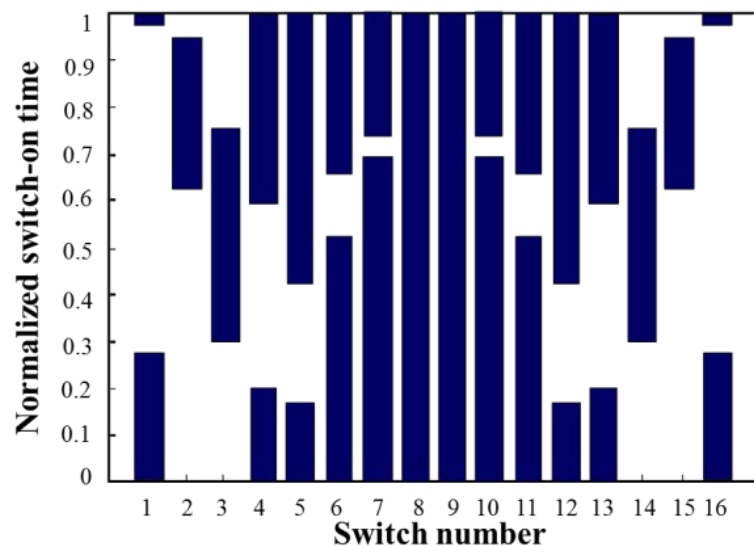
- The fast software control



- Make TMA a versatile and adequate radiation system for modern wireless applications (e.g. Software Defined Radio)

TMA applications

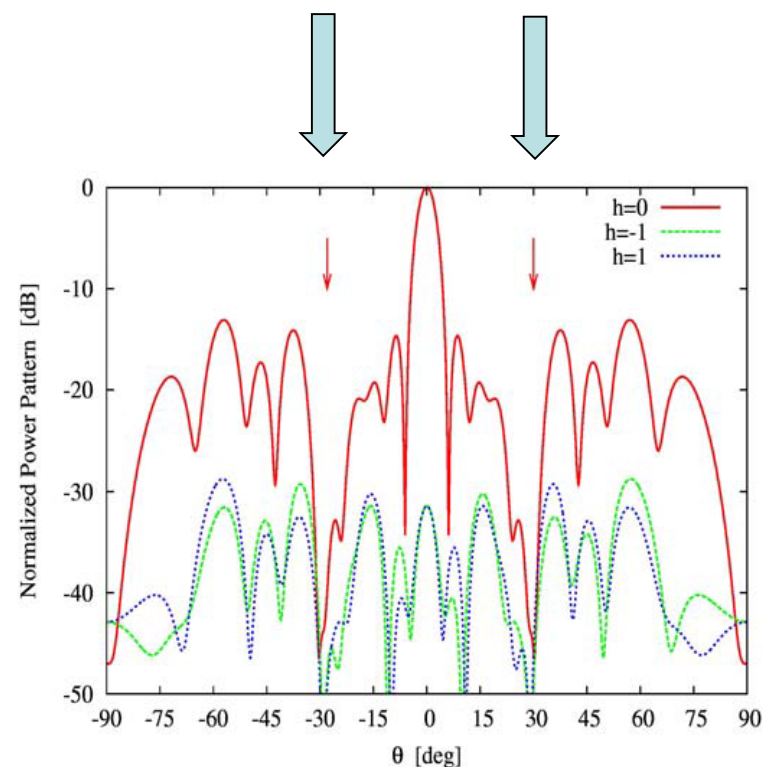
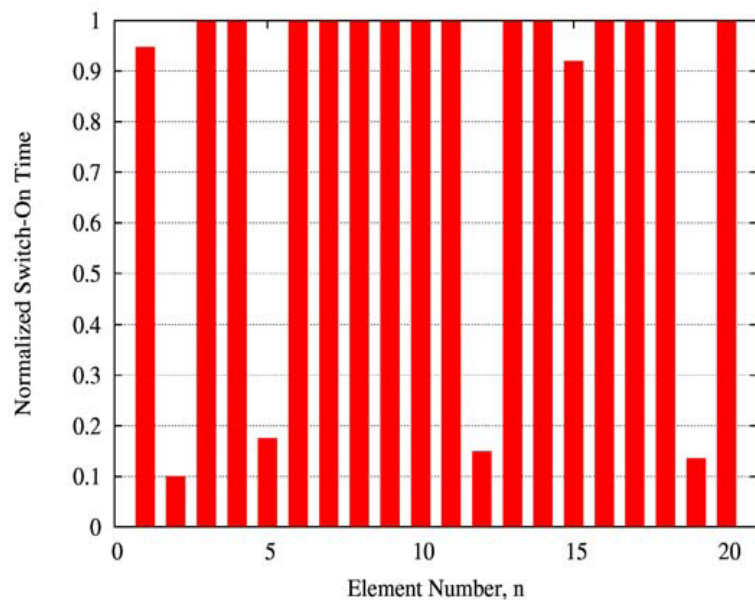
- Reduce self-interference in the broadside direction ($\theta=0^\circ$) due to the desired signal received @ $f_0 \pm hf_M$ ($h \neq 0$) (**Sideband radiation suppression**)



L. Poli, P. Rocca, L. Manica, A. Massa, "Pattern synthesis in time-modulated linear arrays through pulse shifting," *IET Microwaves, Ant. & Prop.*, vol. 4, no. 9, pp. 1157-1164, Sept. 2010

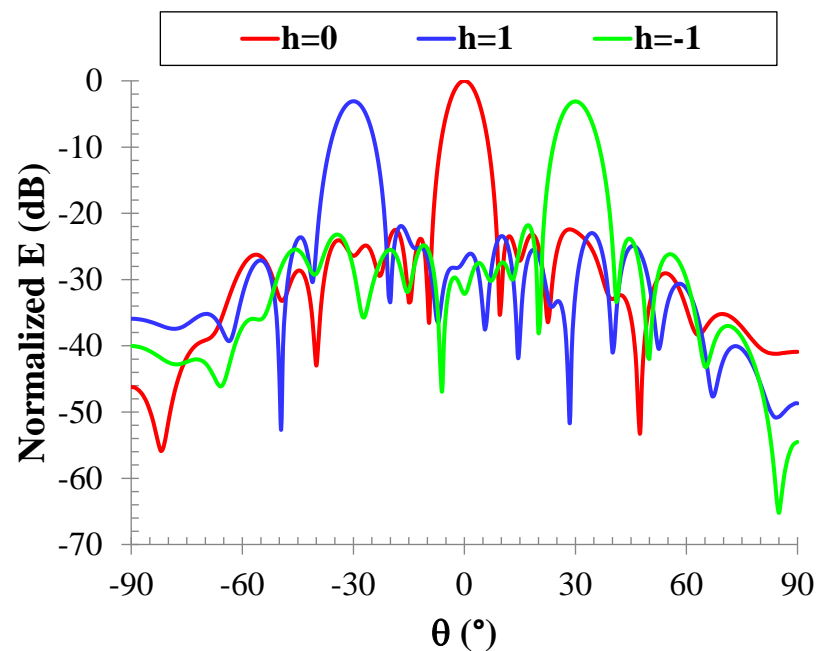
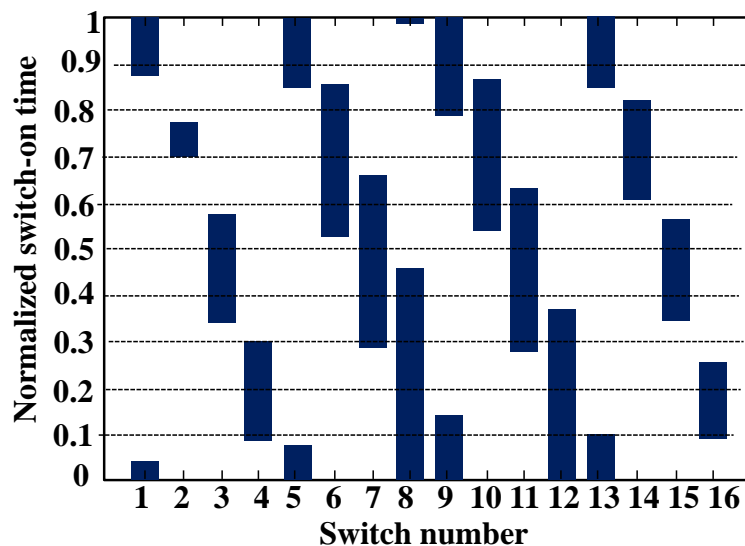
TMA applications

- Suppress undesired interference coming from $\theta \neq 0^\circ$ @ $f_0 \pm hf_M$ ($h = 0, 1, 2, \dots$) (**Harmonic nulling**)



TMA applications

- Exploitation as a multi-channel system (***Harmonic beamforming***)

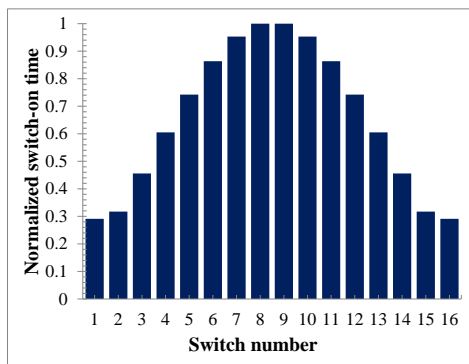


TMA optimization

- TMA design methods focus on control sequence optimization

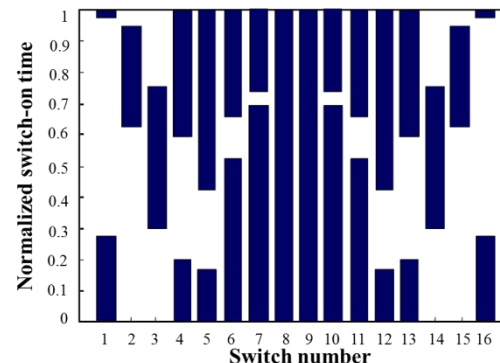
Variable Aperture Size (W. H. Kummer et al. 1963)

Ideal radiating elements
Ideal control switches



design parameter:
impulse length

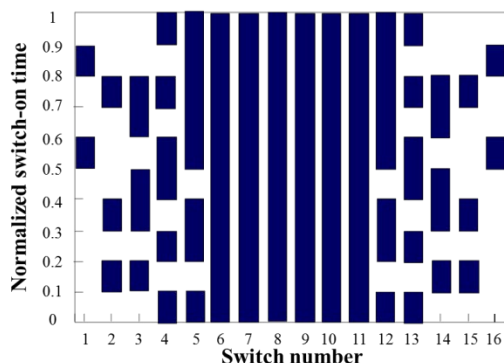
Pulse Shifting (L. Poli et al. 2010)



design parameters:
impulse length
switch-on instant

Binary Optimized Time Sequences

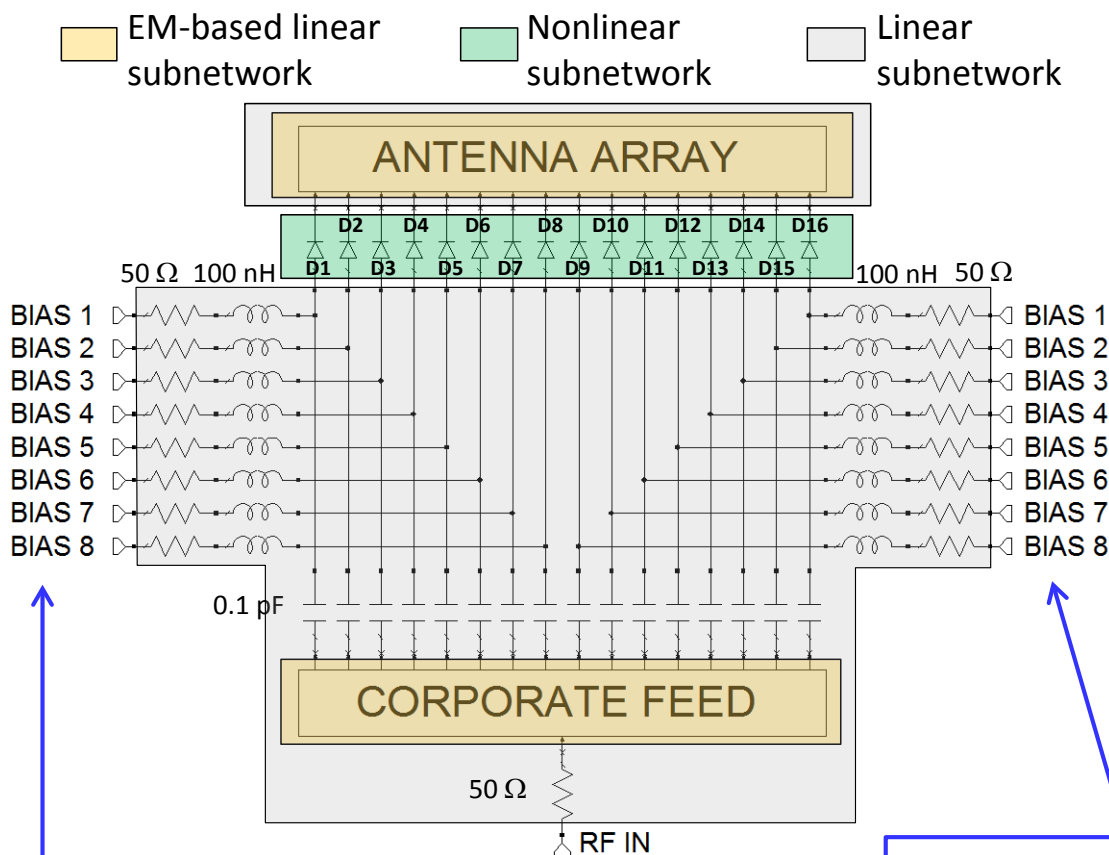
(S. Yang et al. 2005)



design parameter:
impulse sub-intervals

NL/EM TMA co-simulation

Piecewise Harmonic-Balance method

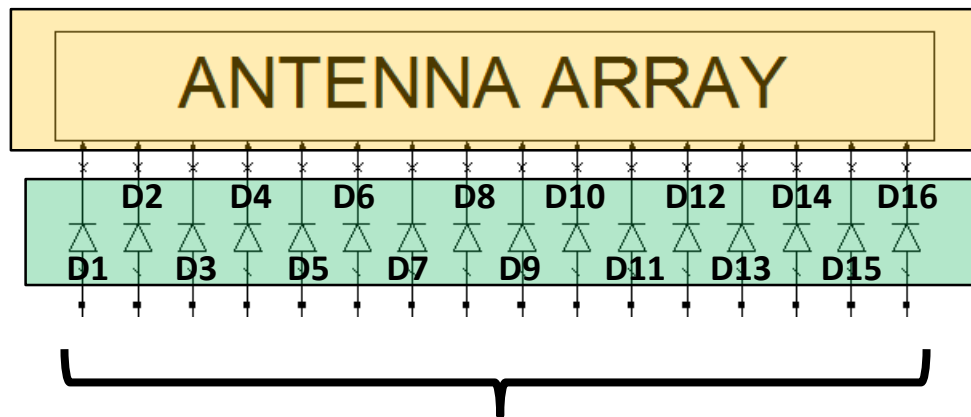


- A **nonlinear** subnetwork, containing the diodes
- A **linear** subnetwork, including
 - the EM-based part (the array and the feeding network, in the present case)
 - the lumped components used for biasing and DC-blocking

Symmetrical bias

NL/EM TMA co-simulation

Modulated far-field evaluation



$$T_M = 2\pi/\omega_M \gg T_0 = 2\pi/\omega_0$$



circuit-envelope HB

time-dependent complex k-th envelope (or modulation law)

fast carrier time

harmonics of the unmodulated regime

$$\mathbf{i}_A^{(i)}(t, t_M) = \text{Re} \left[\sum_{k=1}^{n_H} \mathbf{I}_{A,k}^{(i)}(t_M) \exp(jk\omega_0 t) \right]$$

slow modulation time

$$\mathbf{I}_{A,k}^{(i)}(t_M) = \sum_{h=-N_B}^{N_B} \mathbf{I}_{A,kh}^{(i)} \exp(jh\omega_M t_M)$$

no. of harmonics for modulation spectrum description

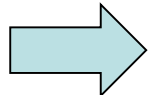
NL/EM TMA co-simulation

Field envelope at the fundamental harmonic

$$\mathbf{E}_1(r, \theta, \phi; t_M) = \frac{\exp(-j\beta r)}{r} \bullet$$

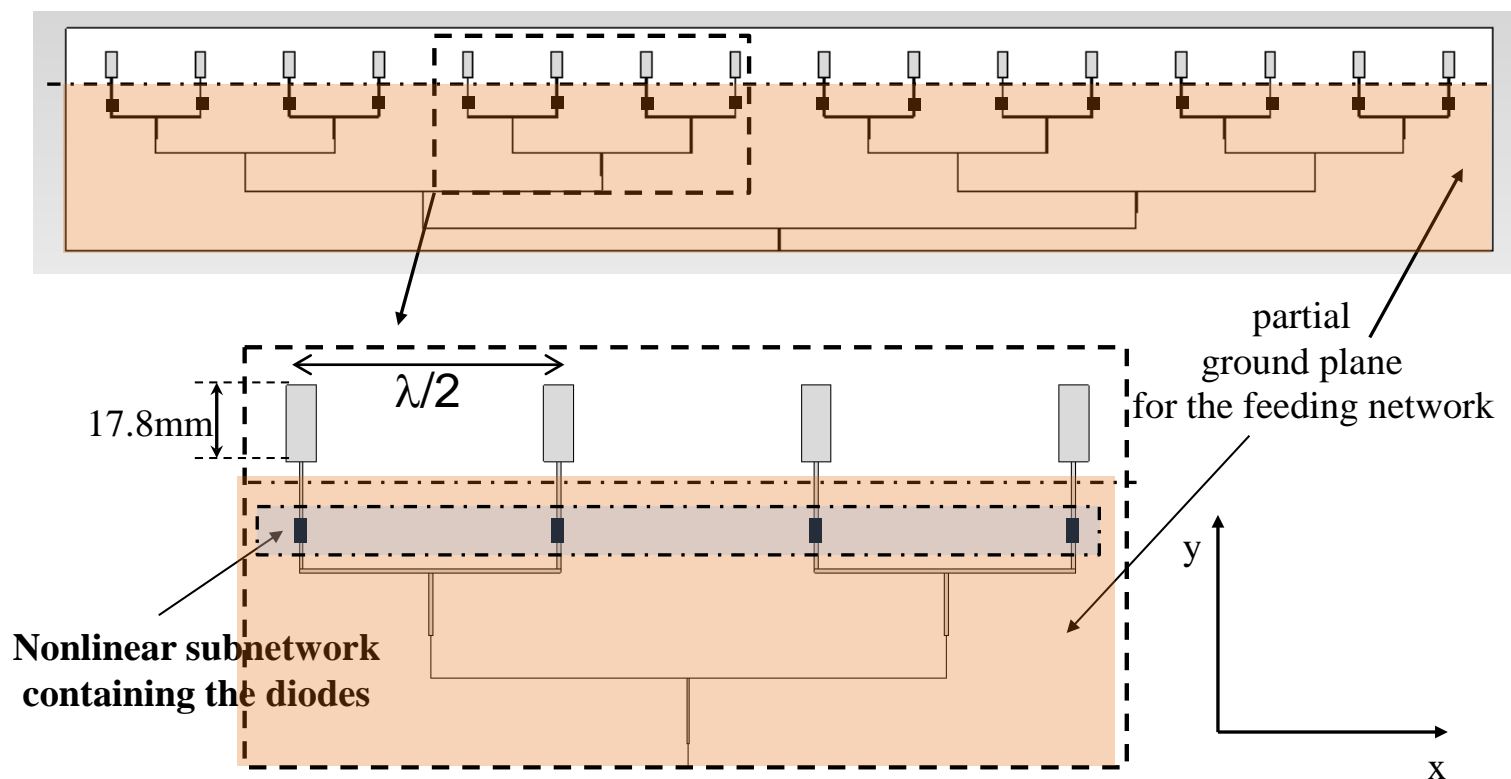
$$\bullet \sum_{i=1}^{n_A} \left[\hat{\theta} A_{\theta}^{(i)}(\theta, \phi; \omega_0) + \hat{\phi} A_{\phi}^{(i)}(\theta, \phi; \omega_0) \right] I_{A,1}^{(i)}(t_M) -$$

$$- j \frac{1}{r} \left[\sum_{i=1}^{n_A} \frac{\partial \left\{ \exp(-j\beta r) \left[\hat{\theta} A_{\theta}^{(i)}(\theta, \phi; \omega) + \hat{\phi} A_{\phi}^{(i)}(\theta, \phi; \omega) \right] \right\}}{\partial \omega} \right]_{\omega=\omega_0} \bullet \left[\frac{dI_{A,1}^{(i)}(t_M)}{dt_M} \right]$$

- $A_{\theta}^{(i)}, A_{\phi}^{(i)}$  **EM data-base**
 - are the scalar components of the normalized field
 - are generated by EM simulation with only the i-th monopole excited by a unit-current sinusoidal source of angular frequency ω_0
- The EM analyses are carried out **once for all**

Co-simulation results

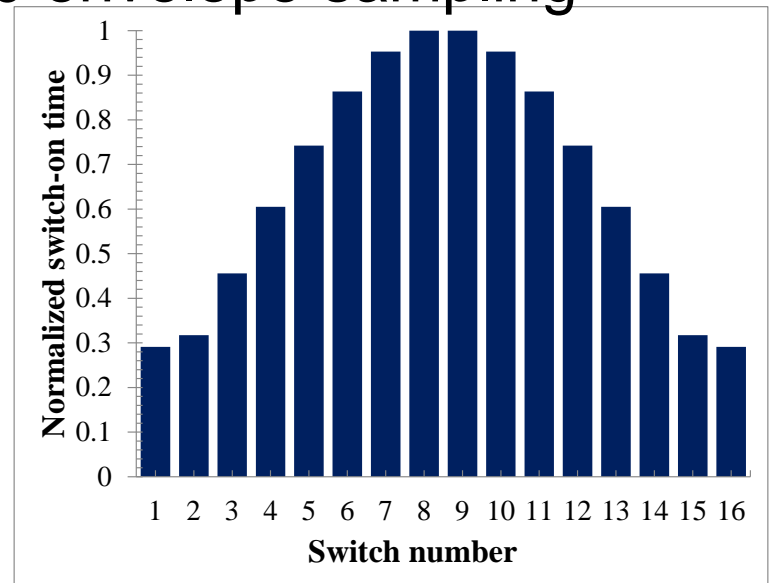
- 16-monopole planar linear array operating at $f_0=2.45$ GHz
- The substrate is a 0.635 mm-thick Taconic RF60A ($\epsilon_r = 6.15$, $\tan\delta=0.0028$ @ 10GHz)



D. Masotti, P. Francia, A. Costanzo, V. Rizzoli, "Rigorous Electromagnetic/Circuit-Level Analysis of Time-Modulated Linear Arrays," *IEEE Trans. Ant. & Prop.*, vol.61, no.11, pp. 5465-5474, Nov. 2013.

TMA with Dolph-Chebyshev pattern

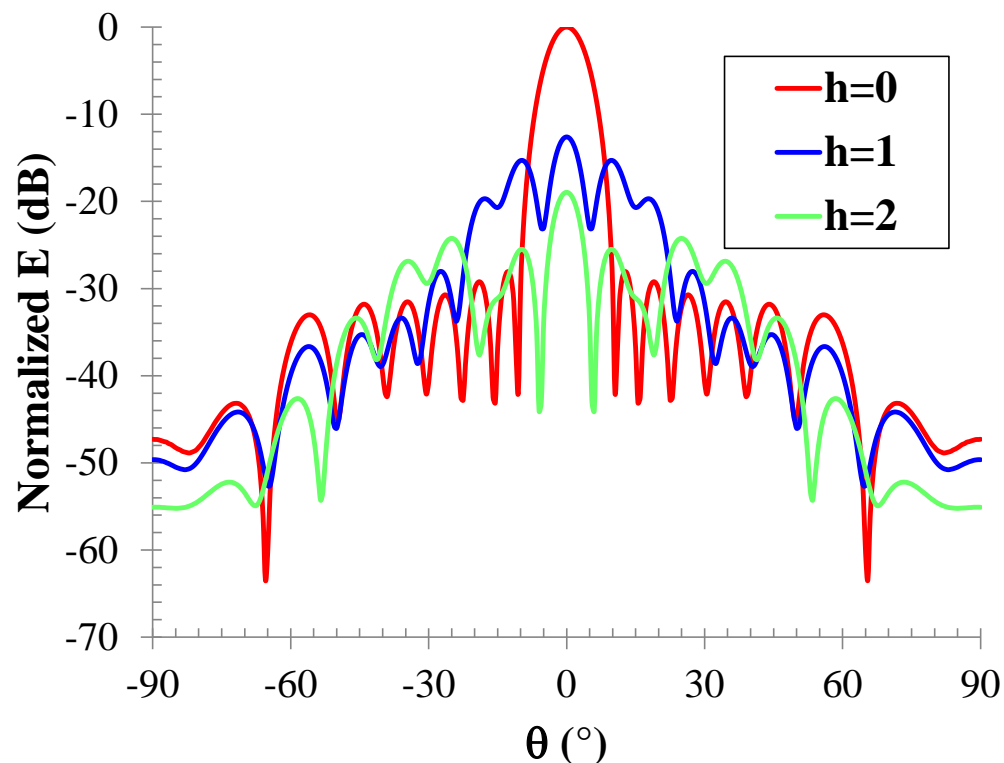
- Sinusoidal carrier $f_0 = 2.45 \text{ GHz}$, $P_{\text{RF}} = 0\text{dBm}$
- Switch modulation frequency $f_M = 10 \text{ kHz}$ ($f_M \ll f_0$)
- Rectangular pulses with repetition period $T_M = 0.1 \text{ ms}$ and amplitude $V_{\text{bias}} = 3 \text{ V}$ are applied at the 8 bias ports (*symmetrical excitation*)
- A uniform sequence of $N_S = 1000$ envelope sampling instants t_n is chosen within the pulse repetition period
- A **VAS** pulse sequence reproducing the Dolph-Chebyshev pattern with side lobe level (SLL) = -30 dB is chosen



Radiation patterns

$$\mathbf{E}_k(t_M) = \sum_{h=-N_B}^{N_B} \mathbf{E}_{kh} \exp(jh\omega_M t_M)$$

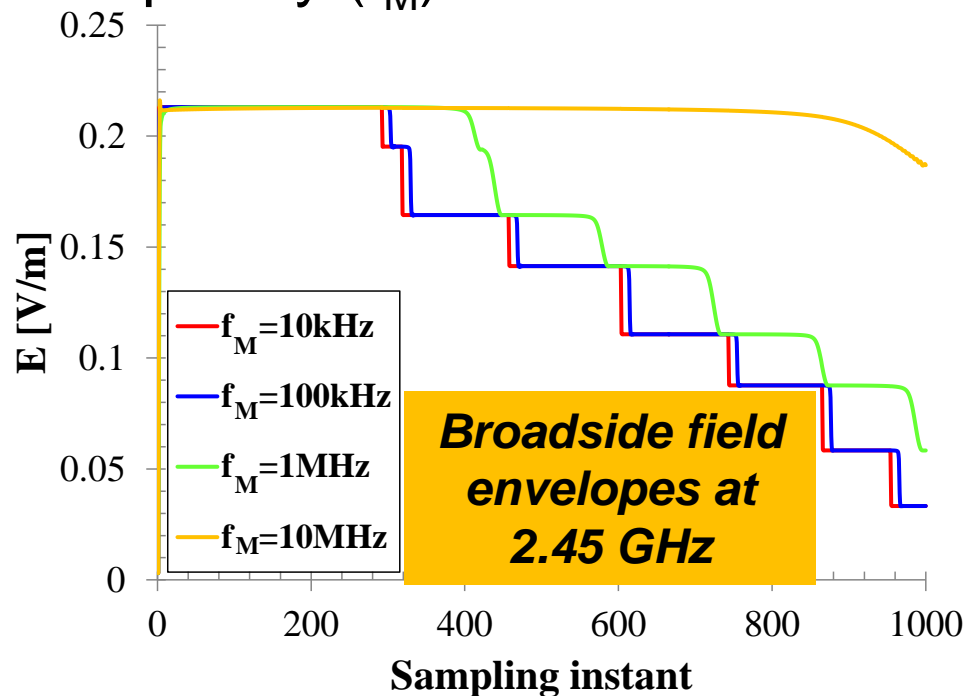
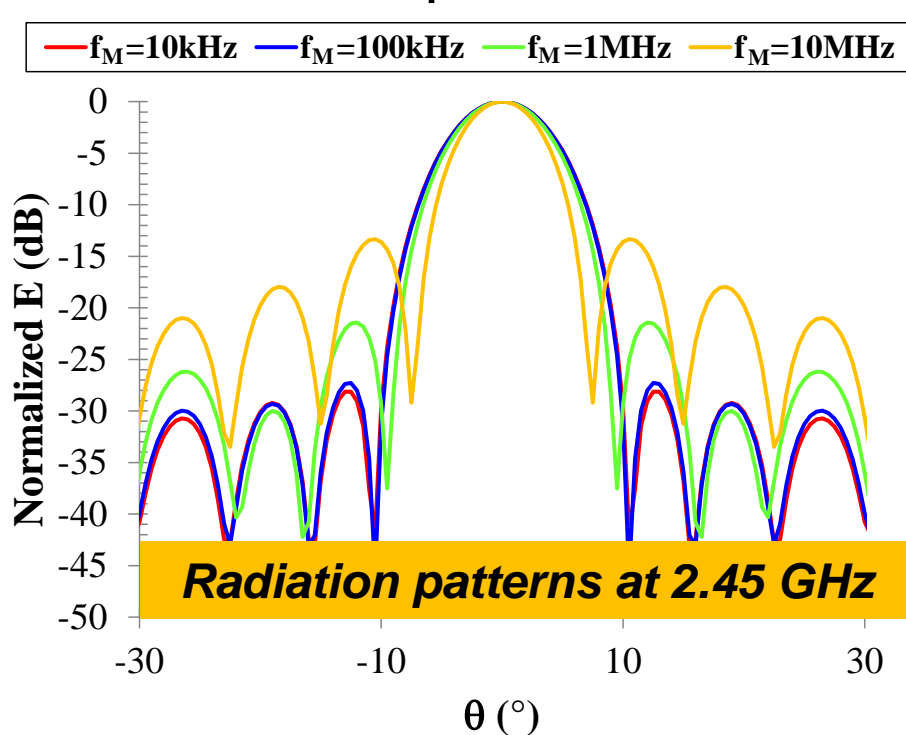
- $k=1, h=0$: 2.45 GHz
fundamental
- $k=1, h=1$: 2.45001 GHz
first harmonic
- $k=1, h=2$: 2.45002 GHz
second harmonic



Known problem of VAS sequences:
unwanted **sideband radiation**

Modulation frequency range

- Control sequence modulation frequency (f_M) variation



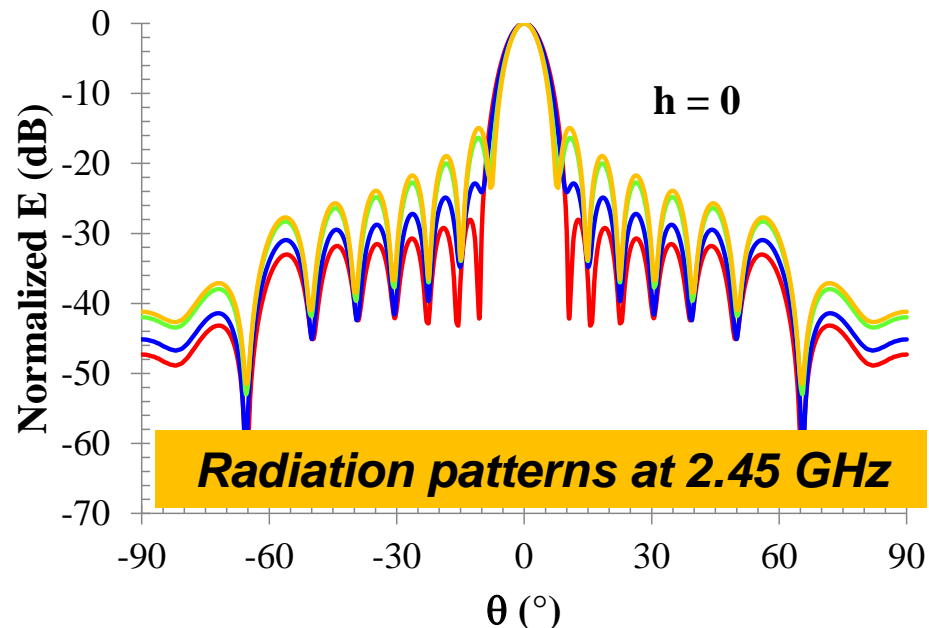
- High values of f_M result in the gradual disappearance of some commutations and unwanted SLL increase

$f_M^{\text{max}} \approx 100\text{kHz}$

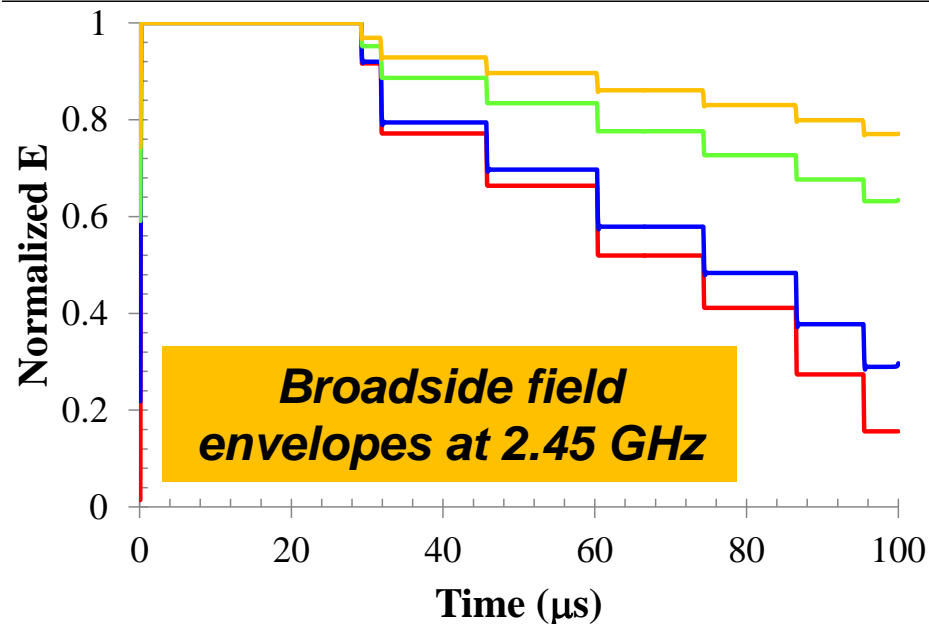
Nonlinear diodes effect

- Input power level (P_{RF}) variation

— $P_{RF}=0\text{dBm}$ — $P_{RF}=10\text{dBm}$ — $P_{RF}=20\text{dBm}$ — $P_{RF}=30\text{dBm}$



— $P_{RF}=0\text{dBm}$ — $P_{RF}=10\text{dBm}$ — $P_{RF}=20\text{dBm}$ — $P_{RF}=30\text{dBm}$

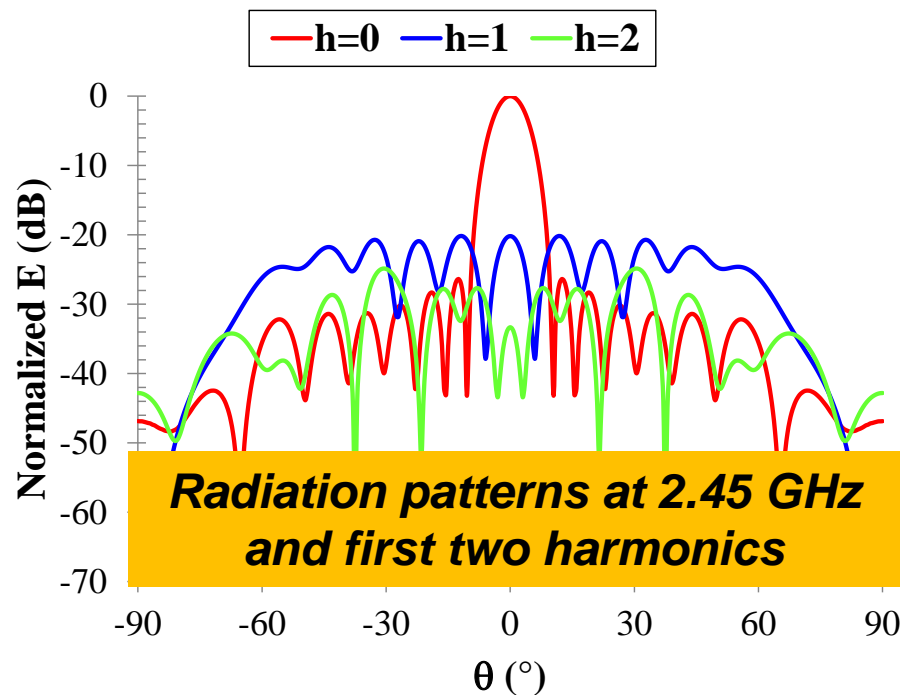
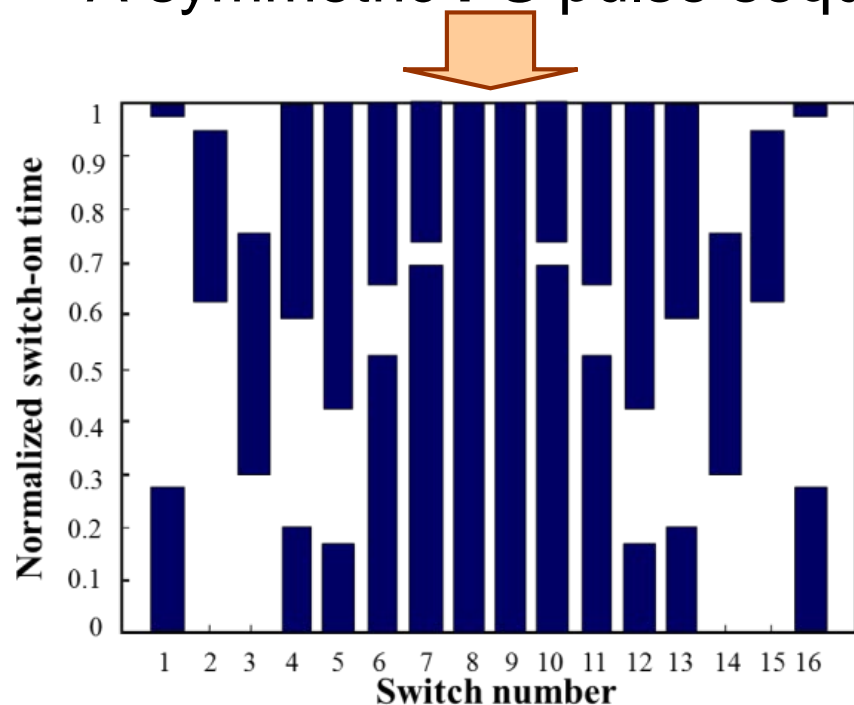


- At high power levels the bias voltage is completely overrun, because a bigger portion of RF signal is rectified by the nonlinear diodes and superimposed to bias

$P_{RF}^{\text{max}} \approx 10\text{dBm}$

TMA with Pulse Shifting pattern

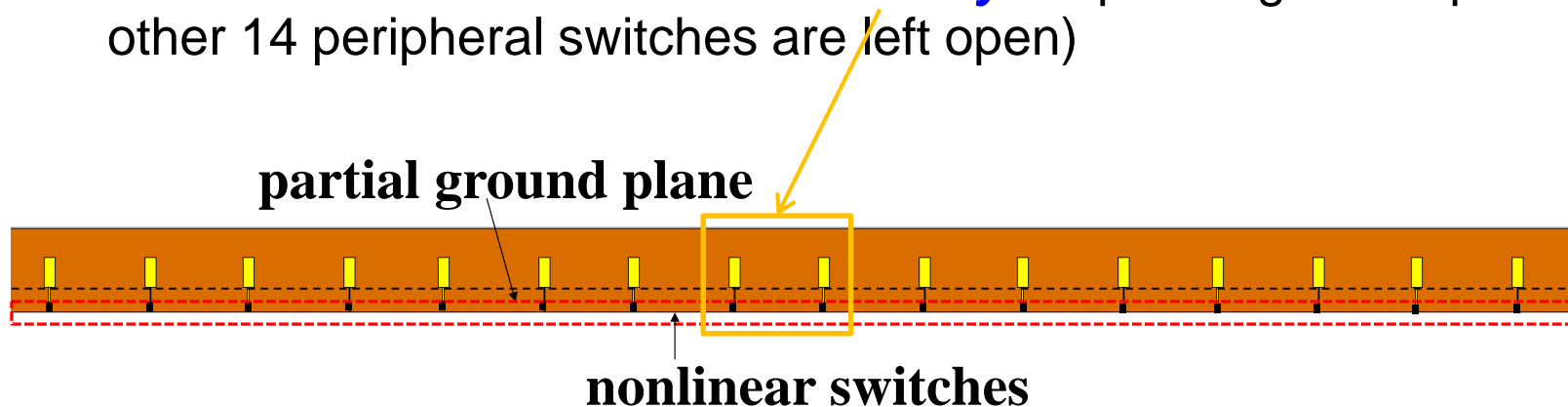
- A symmetric **PS** pulse sequence with SLL = -30 dB is chosen



- Note that the time-consuming EM-based database consisting in the $A_{\theta}^{(i)}$, $A_{\phi}^{(i)}$ coefficients ***is always the same***

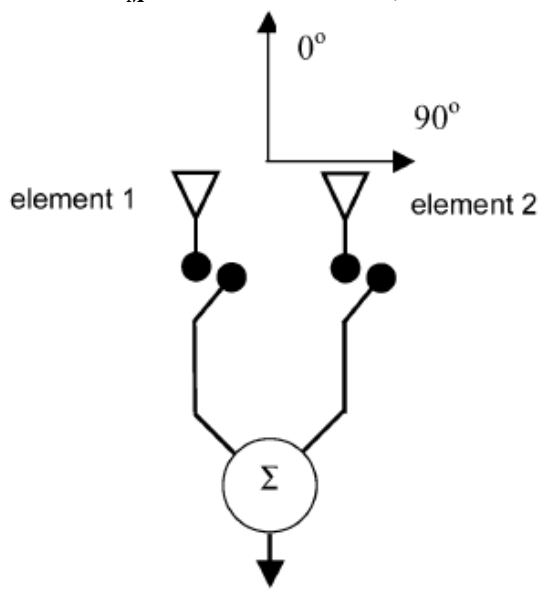
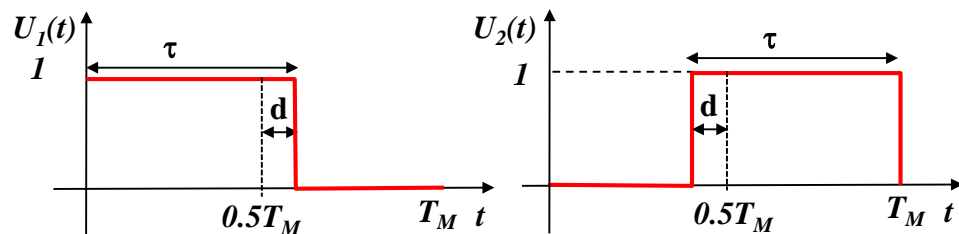
Smart WPT with TMA

- The versatility of TMAs allows a ***smart transfer of power*** by means of a **two-step procedure**
- Scenario: room with randomly placed tagged objects
- **1st step: *Localization of tags***
 - the sole ***two-inner-element sub-array*** is operating in this phase (the other 14 peripheral switches are left open)

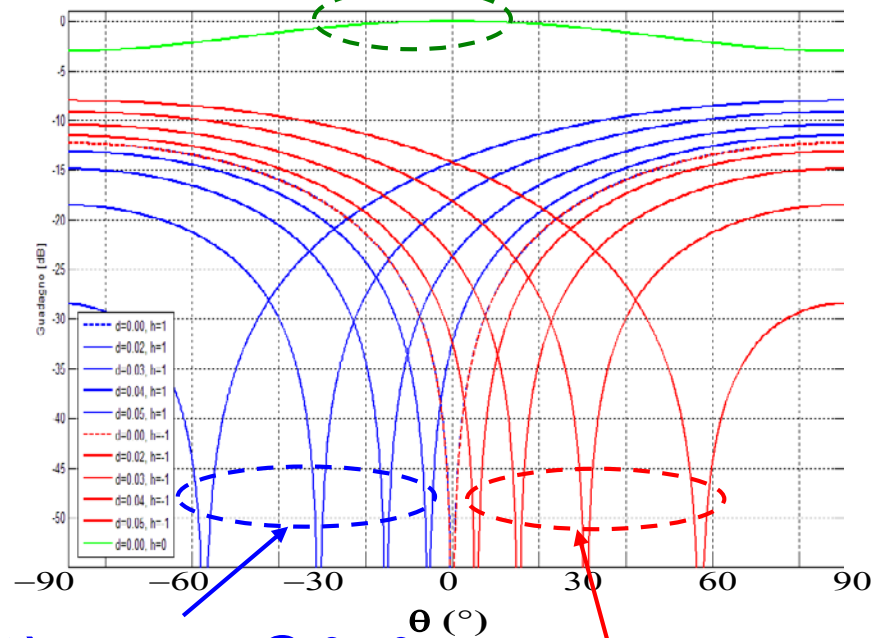


Localization of tags

- By properly driving the switches of an array of two *isotropic* elements **the Δ pattern can be steered**:



Sum (Σ) pattern @ f_0



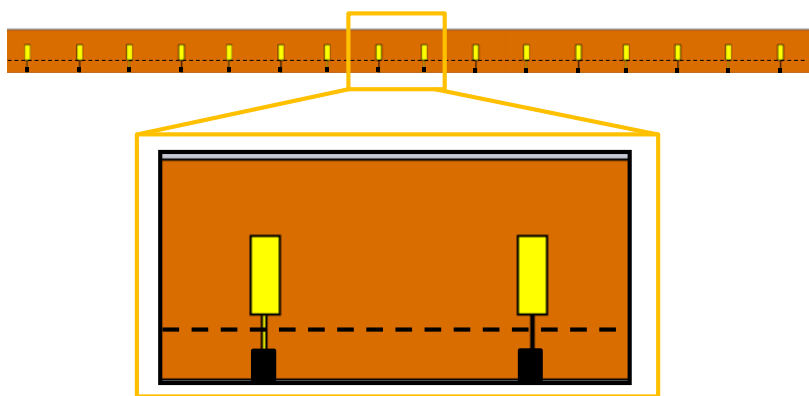
Difference (Δ) pattern @ f_0+f_M

Difference (Δ) pattern @ f_0-f_M

A. Tennant, B. Chambers, "A Two-Element Time-Modulated Array With Direction-Finding Properties," *IEEE Antennas and Wireless Prop. Lett.*, vol. 6, pp. 64-65, 2007

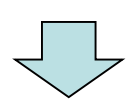
Localization of tags

- By properly driving the two inner switches of two *real* dipoles:

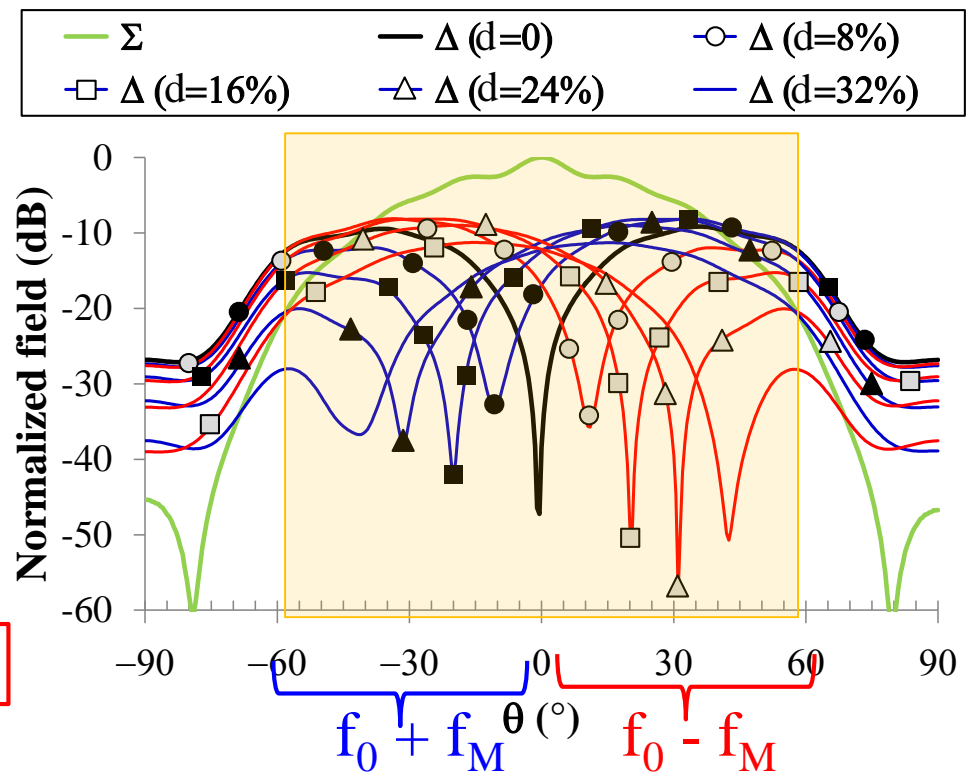


Received Maximum Power Ratio

$$MPR(\theta) = \Sigma_{RSSI}^{dB}(\theta) - \Delta_{RSSI}^{dB}(\theta)$$

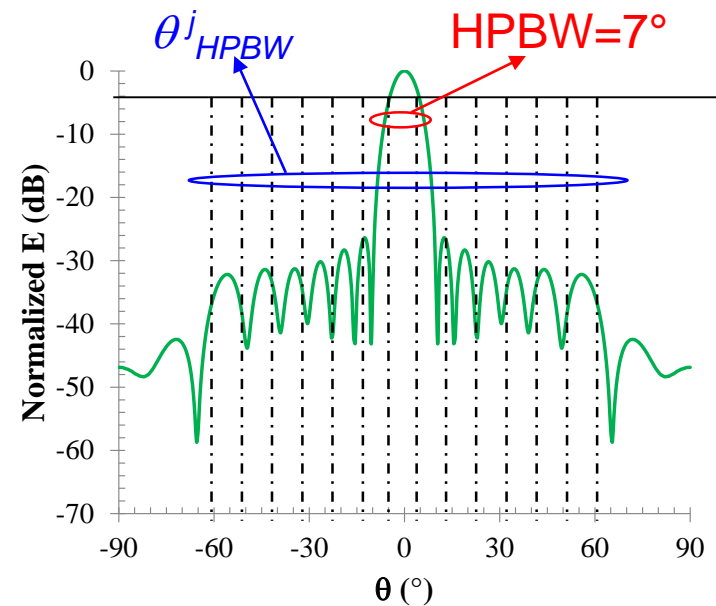


$\theta_{peak}^i; i=1, \dots, N_{tag}$ **List of tags position**



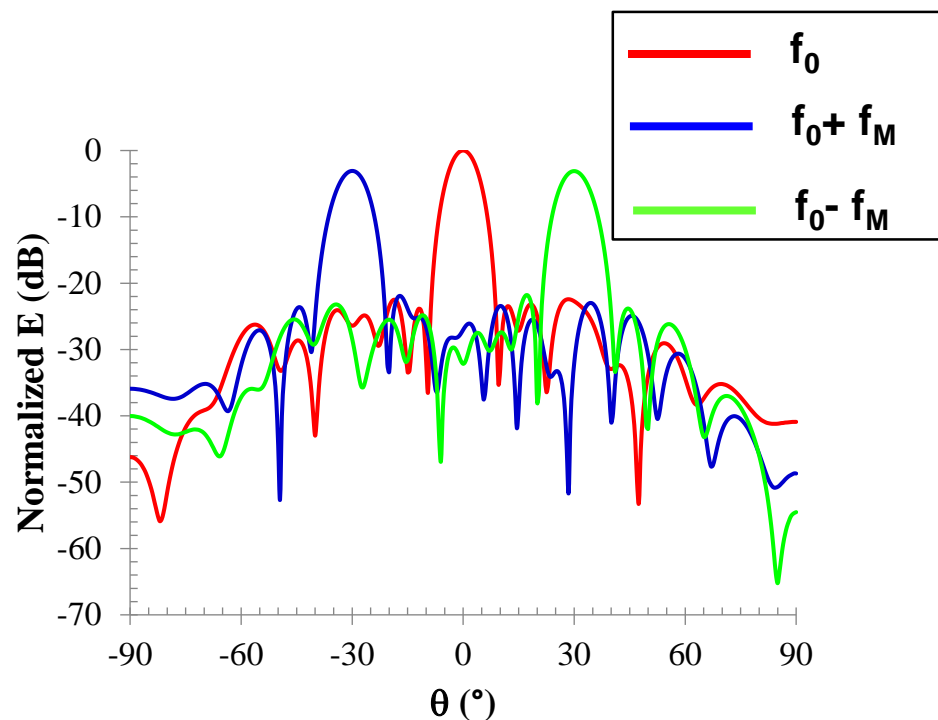
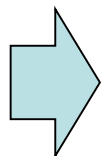
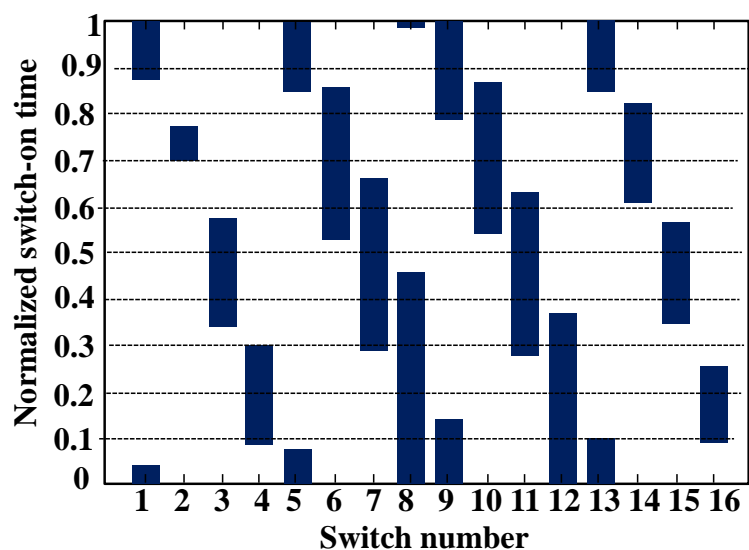
Transfer of power to tags

- Once the tags position has been recorded:
- **2nd step: *Transfer of power to tags***
 - *The whole 16-element array* is driven by proper *pre-loaded control sequences* involving all the switches
 - Possible decision rule:
 - i. split the scanning region ($\theta \in [-60^\circ \div 60^\circ]$) into sectors of amplitude equal to the half power beam width (HPBW)
 - ii. for each θ_{peak} falling in the sector centered around θ_{HPBW} , the pre-loaded control sequence pointing the first harmonic to the θ_{HPBW} direction is used



Transfer of power to tags

- Case 1: θ_{peak} falling into the sectors centered around $\theta_{HPBW} = -30^\circ, 0^\circ, 30^\circ$

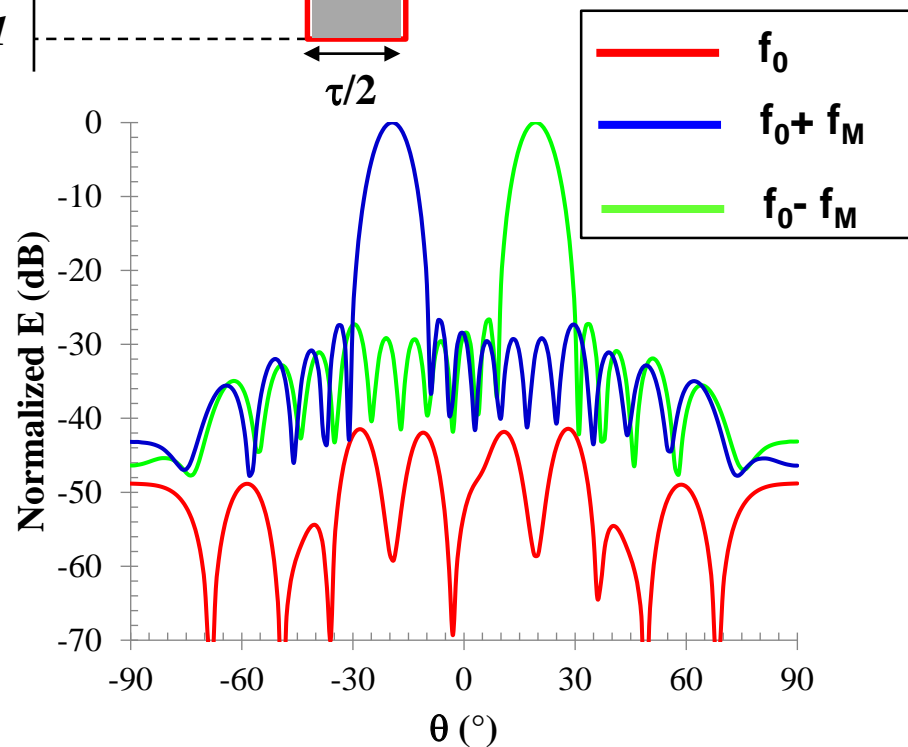
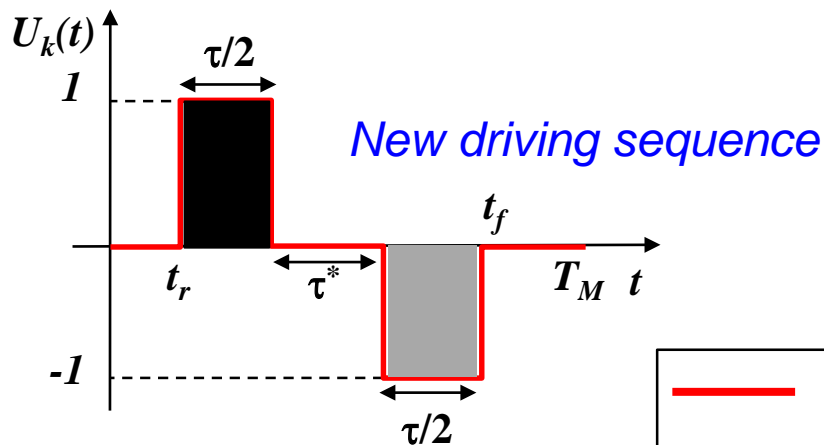
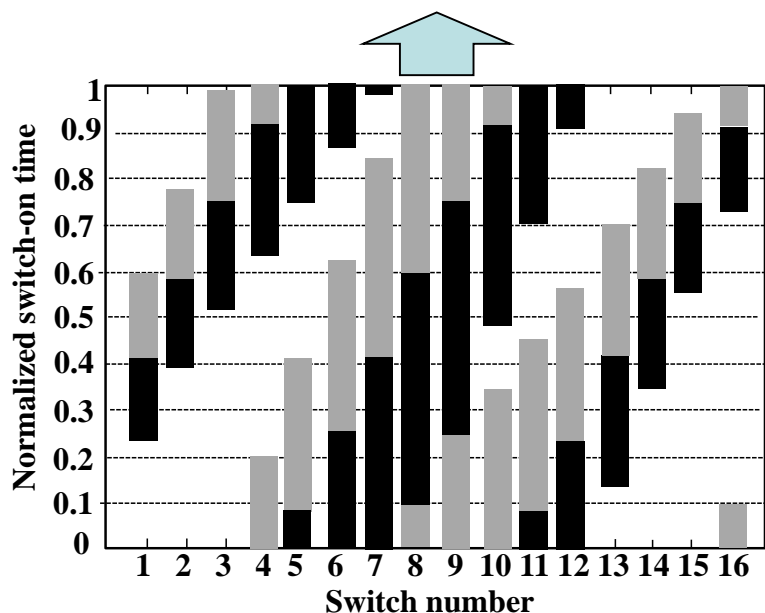


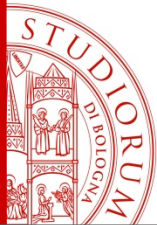
Simultaneous powering of the 3 tags

Transfer of power to tags

- Case 2: θ_{peak} falling into the sectors centered around $\theta_{HPBW} = -20^\circ, 20^\circ$

Fundamental radiation is switched-off





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